



# Quantum basis of the spin manipulation by electric fields

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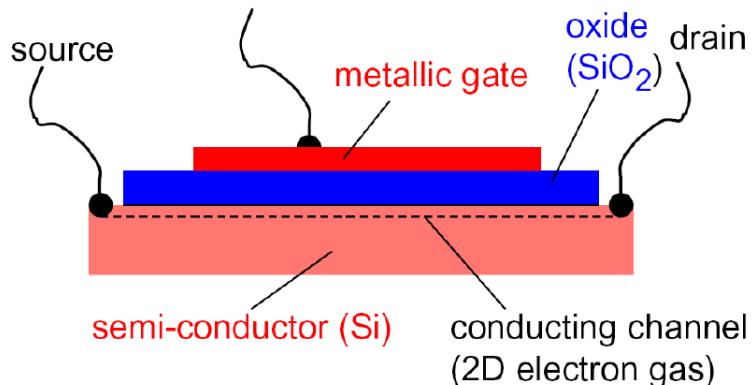
## Idee: Datta and Das Transistor

S. Datta and B. Das (1990) „*Electronic analog of the electro-optic modulator*“

Applied Physics Letters 56 (7): 665–667. (1990)

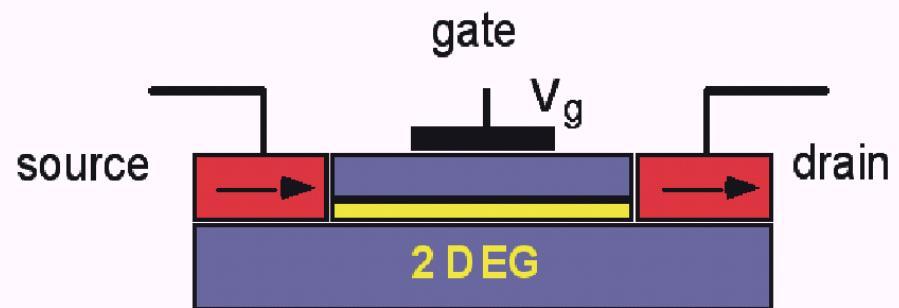
(1)

“Normal” transistor (MOSFET)



(2)

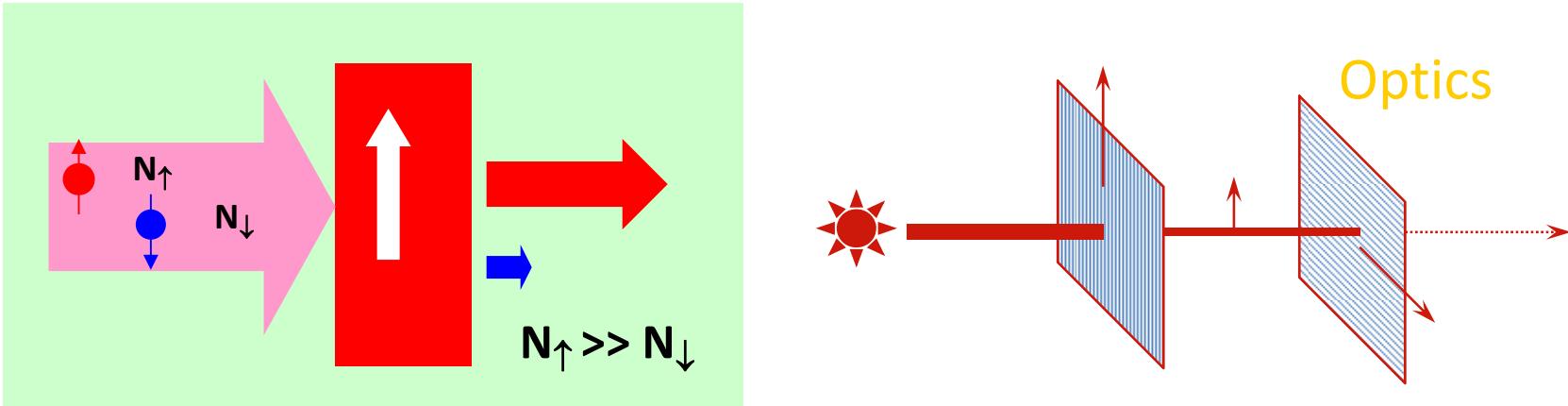
Spin transistor



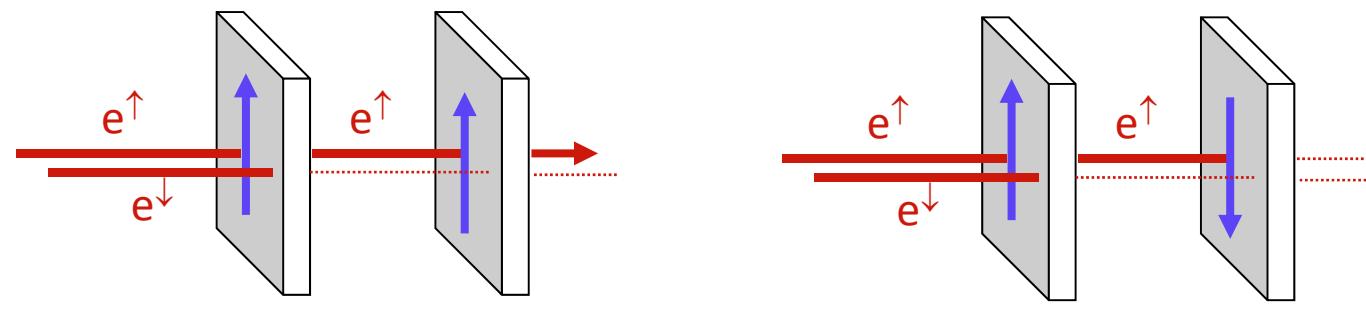
- Gate potential controls the source-drain current
- Used as modulator, amplifier, switch
- Source and drain = FM materials
- Conduction channel = 2DEG
- The gate electric field modulates the electron spin state
- No external magnetic field

Take advantage of the electron spin as a new degree of freedom  
to generate new functionalities and devices

Basic idea: Magnetic materials can be used as **Polarizer** and **Analyzer** of electrons (spin filters)



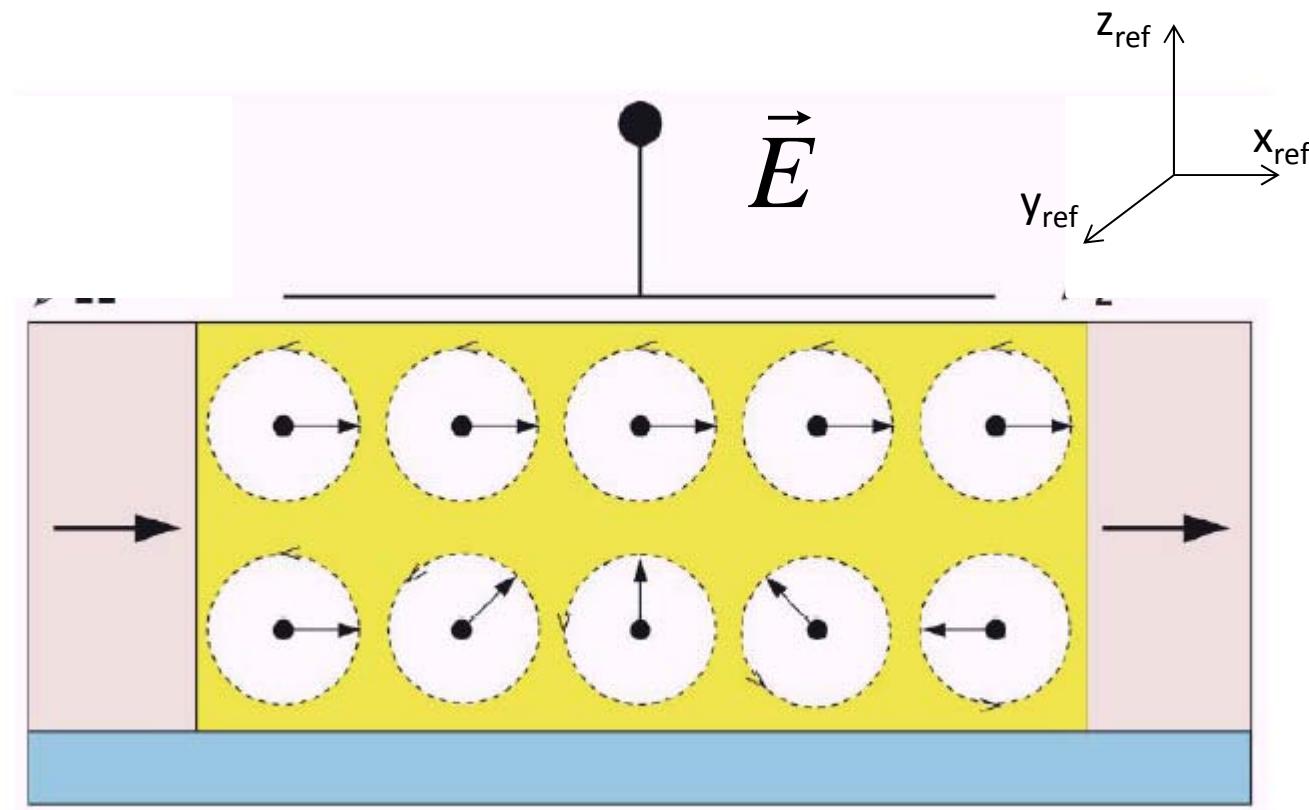
**Spin filters**



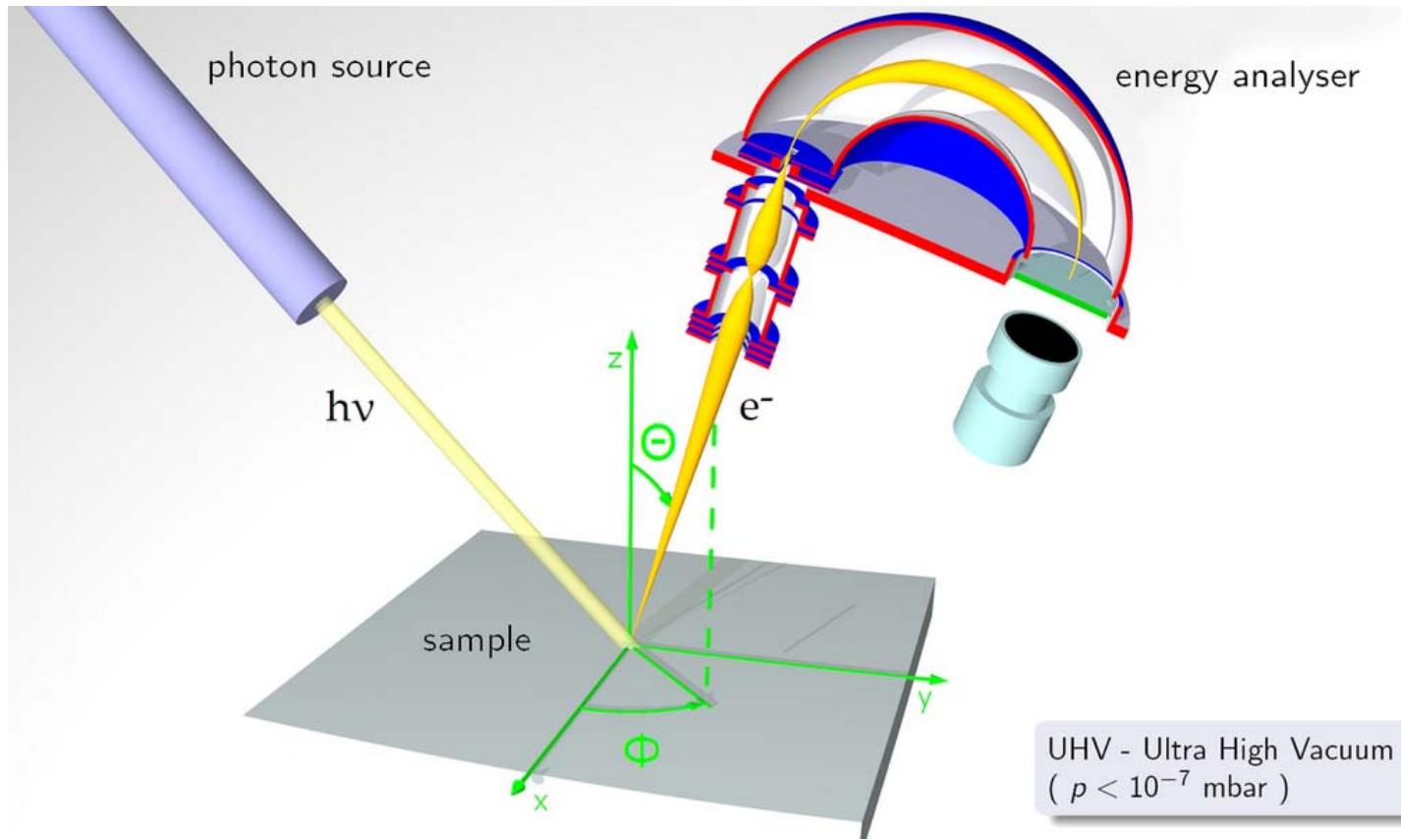
$$s_{\downarrow\downarrow} > s_{\downarrow\uparrow} \Rightarrow r_{\downarrow\downarrow} < r_{\downarrow\uparrow}$$

However, spin currents can be generated otherwise (spin-orbitronics, spin caloritronics...)...

## Spin FET

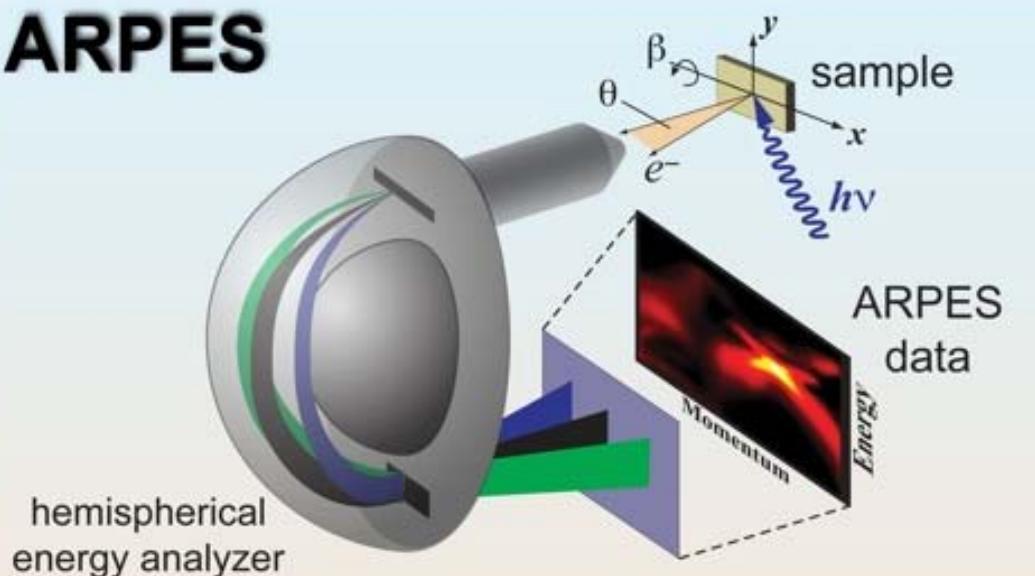


## Photoemission/Angle-resolved photoemission spectroscopy (ARPES)

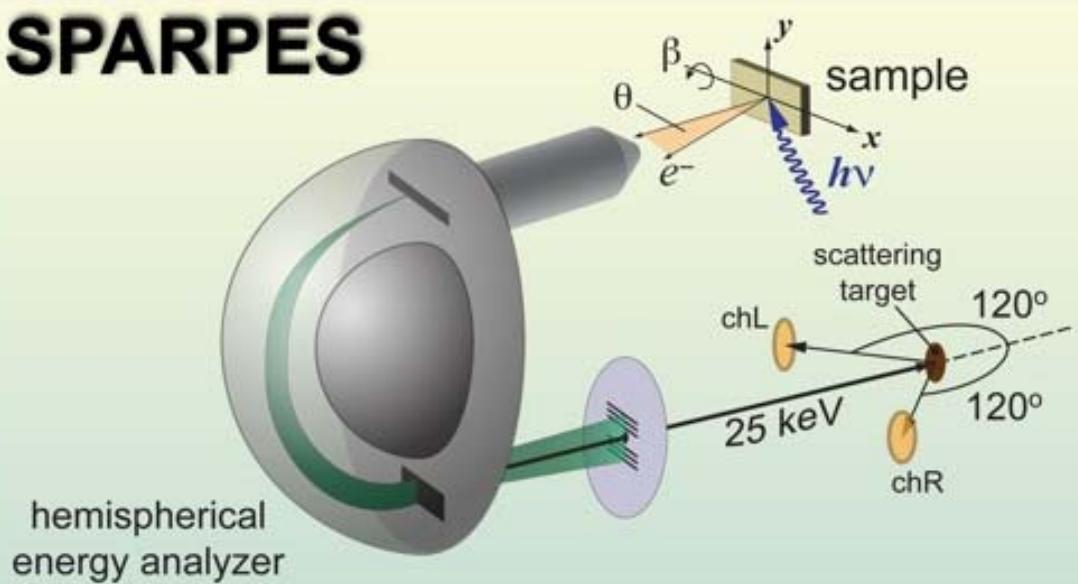


- based on photoelectric effect (X, UV) => XPS, UPS
- direct experimental technique to observe the distribution of the electrons in the reciprocal space of solids =  $E(k)$  for occupied valence states

# ARPES

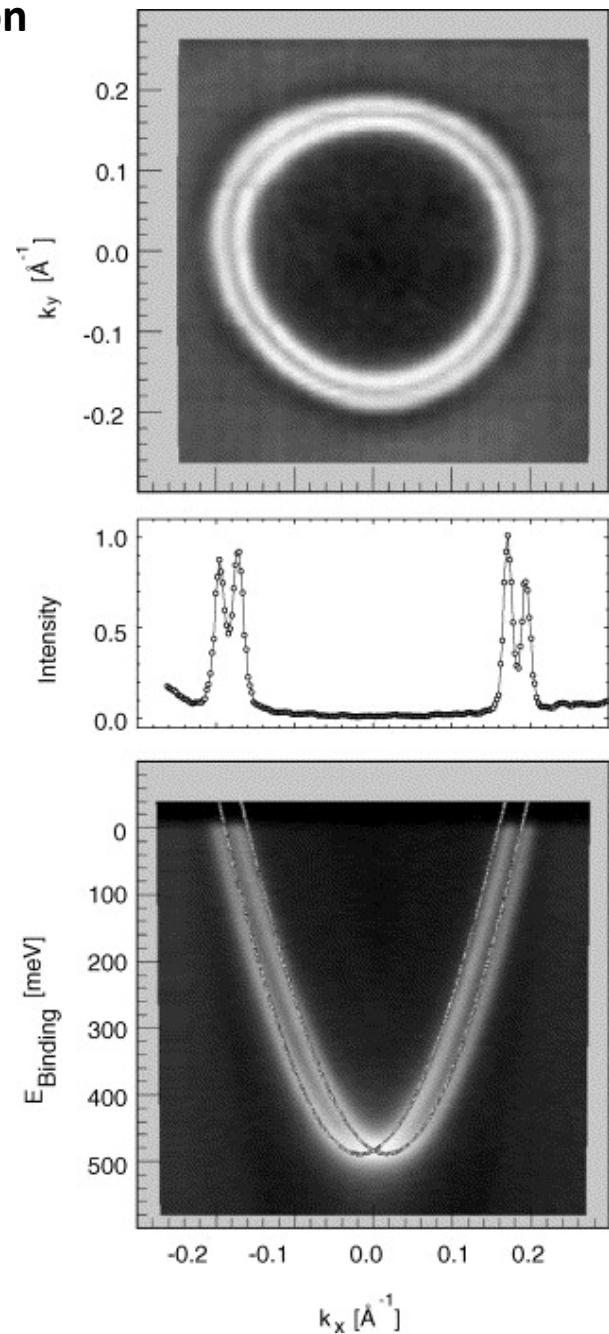


# SPARPES



Electron energy analyzers in ARPES use 2D CCD detector allowing to get the  $E(k)$  of the valence band states in a wide range of emission angles theta in one shot (at a fixed angle beta). The emission angle theta can be used for the calculation of wave vector component  $k_x$  of electron in solid. A rotation of the sample by angle beta produces the 3D data set of experimental photoemission intensity,  $I(E_{kin}, k_x, k_y)$ , where  $E_{kin}$  is the kinetic energy of electron and  $k_y$  is the second in-plane component of the wave-vector calculated from the experimental geometry. In the case of spin-resolved ARPES experiments the 2D CCD detector is replaced by a spin-detector (e.g. classical Mott). This allows an effective separation of the spin-polarized electron beam into two channels: spin-up and spin-down electrons

## Photoemission



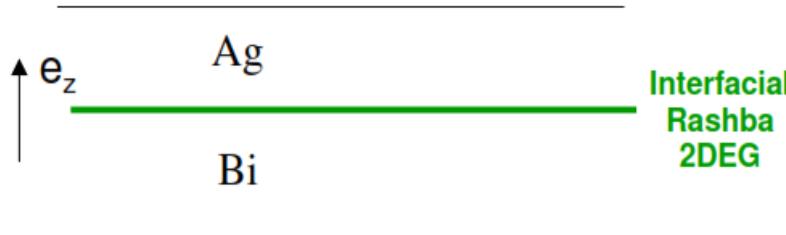
Electron photoemission experiments on a 2D electron (Shockley) state on Au(111) surface –G. Nicolay, F. Reinert, S. Hufner, P. Blaha, Phys. Rev. B 65 (2002) 033407 respectiv F. Reinert, G. Nicolay, S. Schmidt, D. Ehm, S. Hufner, Phys. Rev. B 63 (2001) 115415. The experiments are taken at 30K. Bottom panel: the band structure  $E(k_x)$  along the  $\overline{\Gamma M}$  direction.

Middle panel: cut on  $(k_x, k_y)$  representation (top panel) at  $k_y = 0$

Measuring  $\Delta k \Rightarrow$  Rashba constant  $\alpha$

- $\alpha_R$  from ARPES for materials with important potential in spin-orbitronics (when materials with significant SO are used for generation of spin currents by spin-Hall effects).

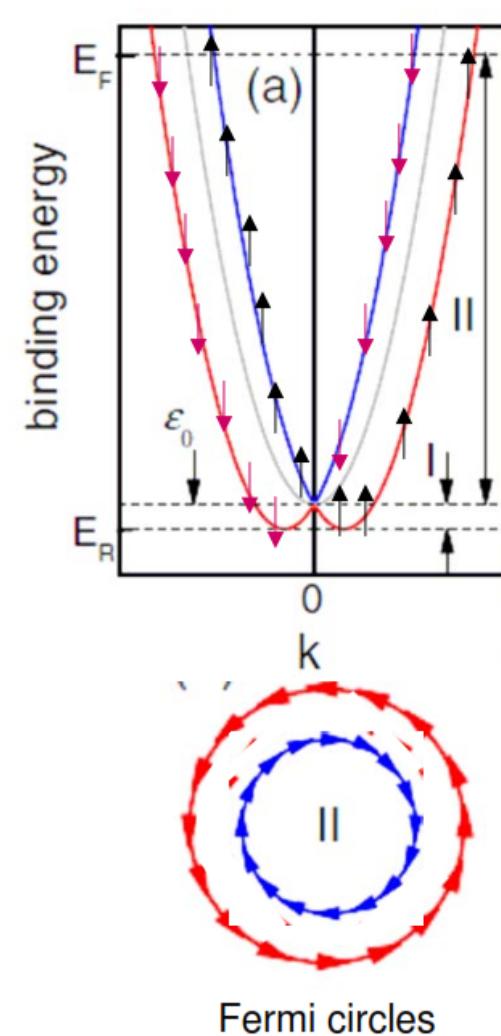
## Rashba effect at interfaces or surfaces of metals



$$\hat{H}_{SO} = \alpha_R \boldsymbol{\sigma} \cdot (\mathbf{k}_{\parallel} \times \mathbf{e}_z), \quad \alpha_R \sim \frac{\partial V}{\partial z}$$

Bi/Ag(111):  $\alpha_R = 3.05 \text{ eV}\text{\AA}^\circ$

Material	$E_R$ (meV)	$k_0$ ( $\text{\AA}^{-1}$ )	$\alpha_R$ ( $\text{eV}\text{\AA}$ )
InGaAs/InAlAs heterostructure	<1	0.028	0.07
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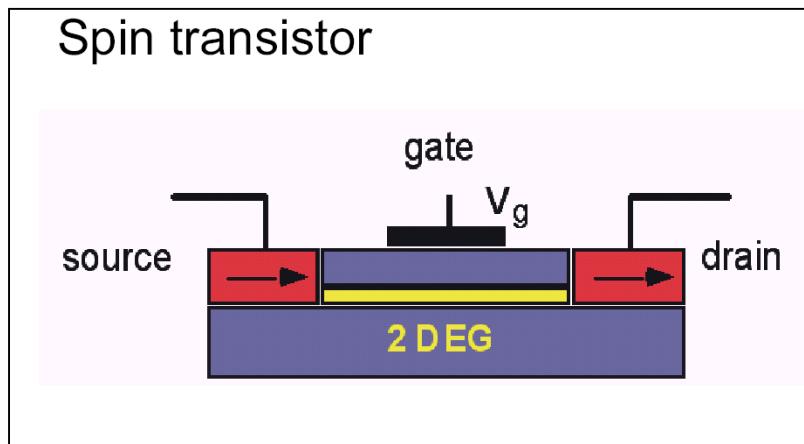
From A. Fert

## Plan

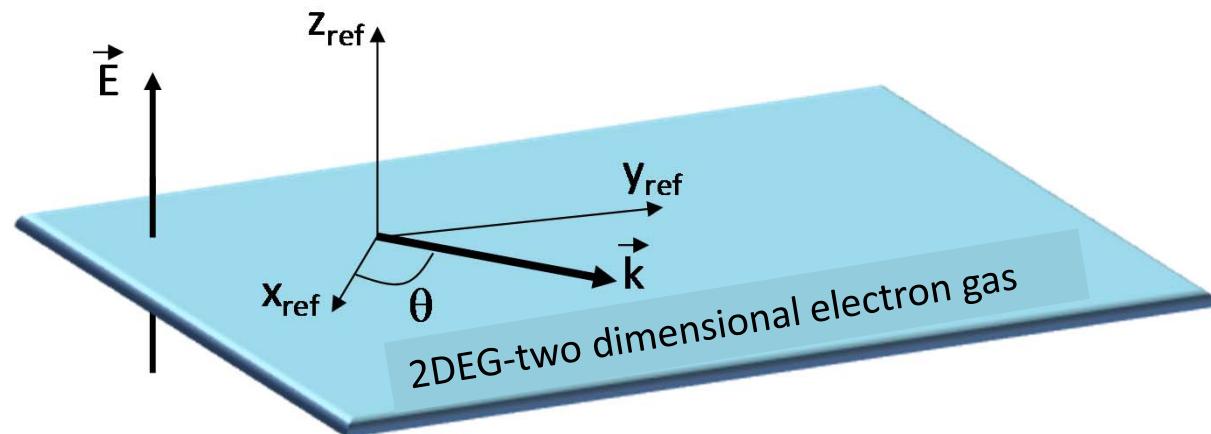
- Starting from the non-relativistic Dirac Hamiltonian, written for the case of a 2D free-electron gas with a confinement direction perpendicular to the propagation direction, we deduce the Rashba Hamiltonian. This strategy allows the direct identification of the Rashba interaction term and interaction constant alpha, as a measure of the spin-orbit interaction. One can thus understand how alpha can be controlled via the external electric field (in Datta-Das spin transistor geometry).
- Within the Heisenberg-Dirac formalism, we solve the stationary Schrodinger equation by diagonalising the spin-orbit Hamiltonian and find the eigenvalues and the stationary eigenfunctions.
  - Analyse the spin-orbit influence on the calculated parabolic  $E(k)$  band structure and discuss how the spin-orbit constant alpha can be extracted from ARPES experiments.
  - Illustrate with some examples of ARPES for materials with important potential in spin-orbitronics (when materials with significant SO are used for generation of spin currents by spin-Hall effects).
- Furthermore, we study the time evolution, solving the time dependent Schrodinger equation. Then, by calculating average values of the spin operators  $S_x, S_y, S_z$  we can demonstrate and discuss the spin precession .

## Problem

- Consider the Datta@Das transistor (Fig.)
- $(x_{\text{ref}}, y_{\text{ref}}, z_{\text{ref}})$  = lab referential;  $z_{\text{ref}} \parallel \vec{E}$  and  $z_{\text{ref}} \perp$  2DEG plane

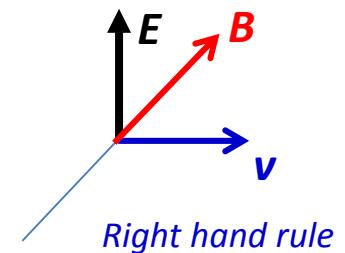


- Source and drain = FM materials
- Conducton channel = 2DEG
- The gate electric field modulates the electron spin state
- No external magnetic field



- The spin precession in external electric field is related to the **spin-orbit interaction** in the 2DEG (Rashba effect)
- The **origin** of the SPIN –ORBIT interaction is **relativistic**
- An electron moving with the velocity  $\mathbf{v}$  in an external field  $\mathbf{E}$  will fill in its own referential an effective magnetic field perpendicular on the direction of moving :

$$\vec{B} = -\frac{\vec{v} \times \vec{E}}{c^2}$$



This magnetic field will lead to the spin Larmor precession

## START

- The Hamiltonian describing the S-O interaction is obtained from the non-relativistic limit of the Dirac equation

$$H_{SO} = \frac{\hbar}{(2m_0c)^2} \vec{\nabla}V \cdot (\hat{\sigma} \times \hat{p})$$

**Non-relativistic Dirac Hamiltonian**

$\hat{\sigma} = (\hat{\sigma}_x, \hat{\sigma}_y, \hat{\sigma}_z)$   
Pauli matrices

For a central potential

$$H_{SO} = \lambda \vec{L} \cdot \vec{S}$$

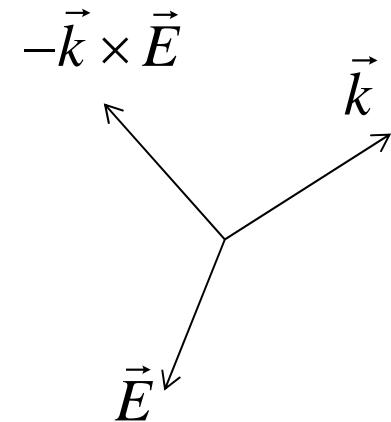
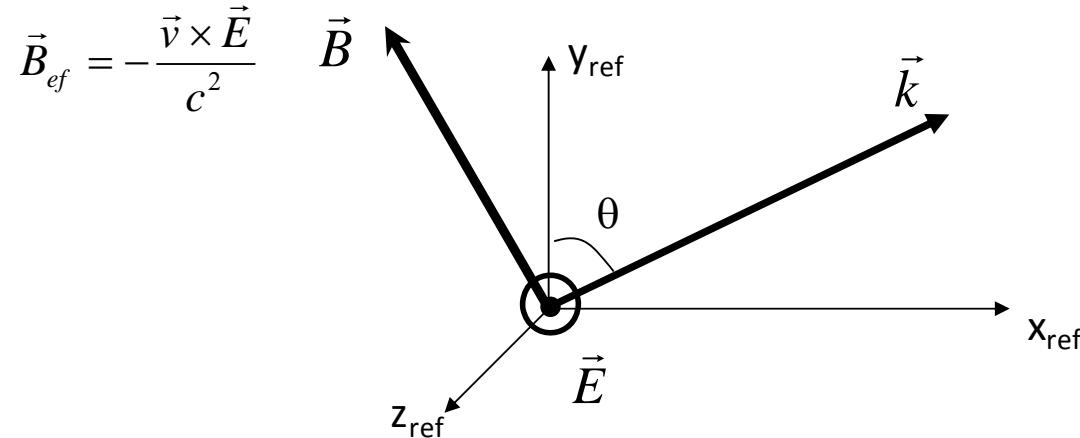
=> Gives the name of the S-O interaction

$\vec{L}$  Orbital momentum

$\vec{S}$  Spin momentum

(I) Starting from the non-relativistic Dirac Hamiltonian, written for the case of a 2D free-electron gas with a confinement direction perpendicular to the propagation direction, we deduce the Rashba Hamiltonian. Then we identify the SO (Rashba) constant.

□ Consider the Datta-Das transistor geometry with  $\vec{E}$  along  $OZ_{ref}$



$$H_{SO} = \frac{\hbar}{(2m_0c)^2} \vec{\nabla}V \cdot (\hat{\sigma} \times \hat{p})$$

Considering the 2DEG with the confinement direction perpendicular to the propagation direction, one can calculate the vector product:

$$\hat{\sigma} \times \hat{p} = \begin{vmatrix} \hat{x} & \hat{y} & \hat{z} \\ \hat{\sigma}_x & \hat{\sigma}_y & \hat{\sigma}_z \\ p_x & p_y & p_z \end{vmatrix}$$

$$\hat{\sigma} \times \hat{p} = \hat{x} (p_z \hat{\sigma}_y - p_y \hat{\sigma}_z) - \hat{y} (p_z \hat{\sigma}_x - p_x \hat{\sigma}_z) + \hat{z} (p_y \hat{\sigma}_x - p_x \hat{\sigma}_y)$$

If  $\vec{E} = -\vec{\nabla}V$  is applied along OZ<sub>ref</sub> axis perpendicular to the 2DEG plane, we would have:

$$\vec{\nabla}V \cdot (\hat{\sigma} \times \hat{p}) = -\frac{\partial V}{\partial z} (\hat{p}_x \hat{\sigma}_y - \hat{p}_y \hat{\sigma}_x) \quad \rightarrow \quad H_{SO} = -\frac{\hbar}{(2m_0c)^2} \frac{\partial V}{\partial z} (\hat{p}_x \hat{\sigma}_y - \hat{p}_y \hat{\sigma}_x)$$

Rashba Hamiltonian

Within the **free-electron approach**, the total Hamiltonian of an electron with the mass m=  $\Sigma$  (**K+SO**)

$$\hat{H}_{SO} = \frac{\hat{p}_x^2 + \hat{p}_y^2}{2m} - \frac{\hbar}{(2m_0c)^2} \frac{\partial V}{\partial z} (\hat{p}_x \hat{\sigma}_y - \hat{p}_y \hat{\sigma}_x) \quad \Leftrightarrow \quad \hat{H}_{SO} = \frac{\hbar^2}{2m} (\hat{k}_x^2 + \hat{k}_y^2) - \frac{\hbar^2}{(2m_0c)^2} \frac{\partial V}{\partial z} (\hat{k}_x \hat{\sigma}_y - \hat{k}_y \hat{\sigma}_x)$$

We denote:

$$\alpha_R = \frac{\hbar^2}{(2m_0c)^2} \frac{\partial V}{\partial z}$$

**SO interaction constant (Rashba constant)**

- is a measure of the spin-orbit interaction.
- alpha can be controlled via the external electric field (in Datta-Das spin transistor geometry).

$$\rightarrow \hat{H}_{SO} = \frac{\hbar^2}{2m} (\hat{k}_x^2 + \hat{k}_y^2) - \alpha_R (\hat{k}_x \hat{\sigma}_y - \hat{k}_y \hat{\sigma}_x)$$

TOTAL  
Rashba Hamiltonian

## Discussion:

### SO interaction constant (Rashba constant)

$$\alpha_R = \frac{\hbar^2}{(2m_0c)^2} \frac{\partial V}{\partial z}$$

$$-\frac{\partial V}{\partial z} = E$$

- The larger is the  $E$  felt by the electron, the larger is the SO-coupling
- In case of atom,  $E \sim Ze$  => SO larger for heavy atoms: Au (Z=79), Pt (Z=78), Pd (Z=46) than for 3D atoms: Cr (Z=24), Fe (Z=26), Co (Z=27), Ni (Z=28).
- SO-coupling exacerbated at the metal surfaces: the breaking of the translational symmetry in surface is equivalent to a potential gradient felt by the electron => electric field.

(II) Within the Heisenberg-Dirac formalism, we solve the stationary Schrodinger equation by diagonalising the spin-orbit Hamiltonian and find the eigenvalues and the stationary eigenfunctions.

START:  $\hat{H}_{SO} = \frac{\hbar^2}{2m} (\hat{k}_x^2 + \hat{k}_y^2) - \alpha_R (\hat{k}_x \hat{\sigma}_y - \hat{k}_y \hat{\sigma}_x)$

**TOTAL**  
Rashba Hamiltonian

The  $\hat{k}_x, \hat{k}_y$  operator commute with  $\hat{H}$  then the eigenfunctions of the system can be:

$$|\Psi\rangle = e^{i(k_x x + k_y y)} (C_1 |+\rangle + C_2 |-\rangle) = e^{i\vec{k}_\parallel \vec{r}} (C_1 |+\rangle + C_2 |-\rangle)$$

$(|+\rangle, |-\rangle)$

- Represent the UP and DN states of the z component of the spin
- They are orthonormal

**Obs:** The z direction in the electron referential is given by the direction of the effective magnetic field  $B_{eff}$ . This represents the magnetic field quantization axis and leads to diagonal  $\sigma_z$ .

- Within this representation we have:

*(see Blundel 2)*

$$\hat{\sigma}_x = \frac{\hbar}{2} \begin{pmatrix} 0 & 1 \\ 1 & 0 \end{pmatrix} \quad \hat{\sigma}_y = \frac{\hbar}{2} \begin{pmatrix} 0 & -i \\ i & 0 \end{pmatrix} \quad \hat{\sigma}_z = \frac{\hbar}{2} \begin{pmatrix} 1 & 0 \\ 0 & -1 \end{pmatrix}$$

The matrix form of the Hamiltonian:

$$\hat{H} = \hat{H}_{FP} + \hat{H}_{SO}$$

Free-particle term:

$$\hat{H}_{ij} = \left\langle i \left| \frac{\hbar^2 k_{||}^2}{2m} \right| j \right\rangle \quad |i\rangle, |j\rangle = |+\rangle, |-\rangle$$

and take into account the orthonormalized conditions

$$\rightarrow \hat{H}_{FP} = \begin{pmatrix} \frac{\hbar^2 k_{||}^2}{2m} & 0 \\ 0 & \frac{\hbar^2 k_{||}^2}{2m} \end{pmatrix}$$

Spin-orbit term:

$$\hat{H}_{SO} = -\alpha_R \left[ k_x \begin{pmatrix} 0 & -i \\ i & 0 \end{pmatrix} - k_y \begin{pmatrix} 0 & 1 \\ 1 & 0 \end{pmatrix} \right] = \begin{pmatrix} 0 & \alpha_R(k_y + ik_x) \\ \alpha_R(k_y - ik_x) & 0 \end{pmatrix}$$

Total Hamiltonian:

$$\hat{H} = \begin{pmatrix} \frac{\hbar^2 k_{||}^2}{2m} & \alpha_R(k_y + ik_x) \\ \alpha_R(k_y - ik_x) & \frac{\hbar^2 k_{||}^2}{2m} \end{pmatrix}$$

Non-diagonal  $\Rightarrow |+\rangle, |-\rangle$  are not eigenstates (stationary states) of the system

**Eigenvalues:**

$$\det(\hat{H} - \lambda \hat{I}) = 0$$

$\Leftrightarrow$

$$\begin{vmatrix} \frac{\hbar^2 k_{\parallel}^2}{2m} - \lambda & \alpha_R (k_y + ik_x) \\ \alpha_R (k_y - ik_x) & \frac{\hbar^2 k_{\parallel}^2}{2m} - \lambda \end{vmatrix} = 0$$

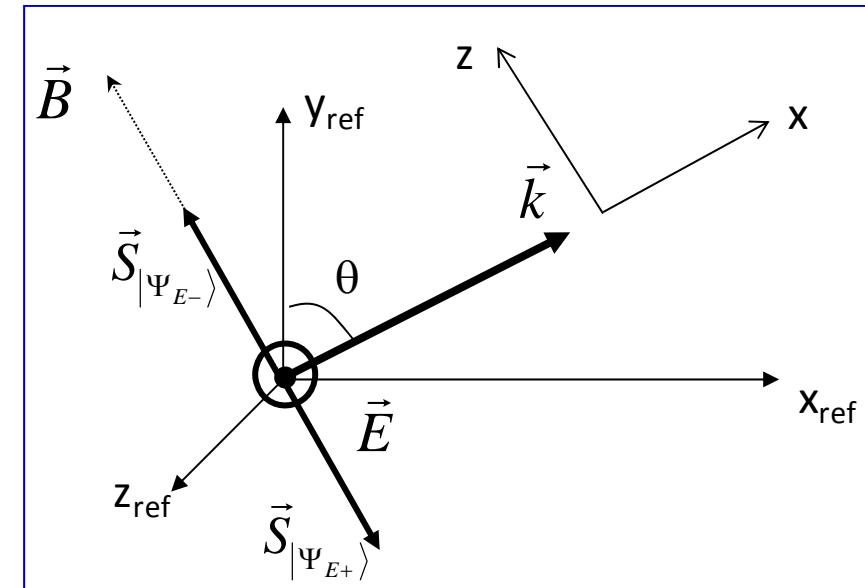
$$\left( \frac{\hbar^2 k_{\parallel}^2}{2m} - \lambda \right)^2 = \alpha_R^2 (k_y + ik_x)(k_y - ik_x) = \alpha_R^2 (k_y^2 + k_x^2) = \alpha_R^2 k_{\parallel}^2$$

$$\lambda = \frac{\hbar^2 k_{\parallel}^2}{2m} \pm \alpha_R |k_{\parallel}|$$

$$\rightarrow E_{\pm}(k_{\parallel}) = \frac{\hbar^2 k_{\parallel}^2}{2m} \pm \alpha_R |k_{\parallel}|$$

- **The eigenvalues of the Rashba Hamiltonian**
- Correspond to a 2 state system (spin parallel and antiparallel to  $B_{\text{eff}}$ )

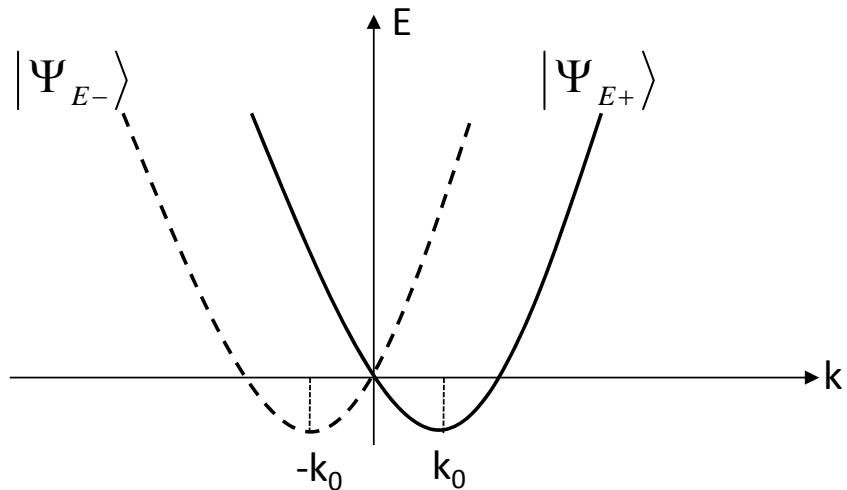
$$\begin{cases} \angle(\vec{k}_{\parallel}, S_{|\Psi_{-}\rangle}) = \frac{\pi}{2} \\ \angle(\vec{k}_{\parallel}, S_{|\Psi_{+}\rangle}) = -\frac{\pi}{2} \end{cases}$$



Vector diagram of eigenfunctions

- SO influence on the parabolic  $E(k)$  band structure
- How the spin-orbit constant alpha can be extracted from ARPES experiments.

$$E_{\pm}(k_{\parallel}) = \frac{\hbar^2 k_{\parallel}^2}{2m} \pm \alpha_R |k_{\parallel}|$$



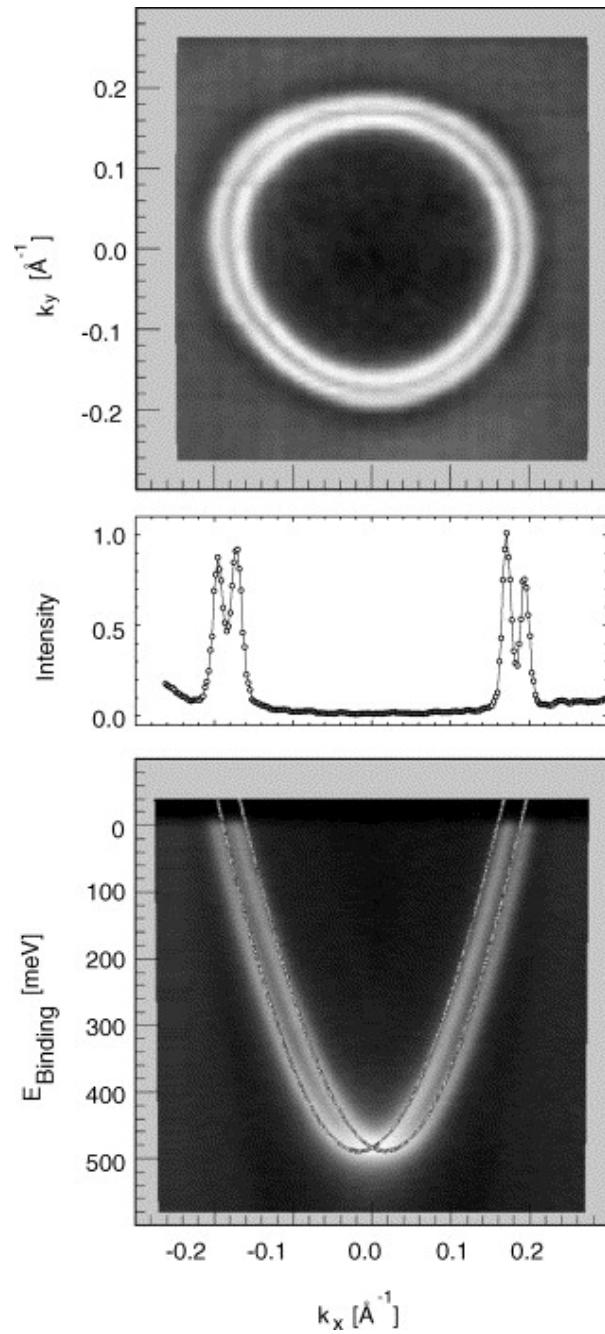
Parabola minimum get from:

$$\frac{\partial E}{\partial k} = 0 \quad \rightarrow \quad k_0 = \frac{m\alpha_R}{\hbar^2} \quad \rightarrow \quad \Delta k = 2k_0 = \frac{2m\alpha_R}{\hbar^2}$$

- Measuring  $\Delta k$  one can get  $\alpha_R$

**OBS:** Because  $\alpha_R$  is small (1 order of magnitude smaller than  $E_F$ ) high resolution of analyzer is required in photoemission experiments to observe the split

$$\alpha_R = 1 \text{ meV} \rightarrow \Delta k \sim 10^{-15} \text{ m}^{-1} = 10^{-5} \text{ \AA}^{-1}$$



Electron photoemission experiments on a 2D electron (Shockley) state on Au(111) surface –G. Nicolay, F. Reinert, S. Hufner, P. Blaha, Phys. Rev. B 65 (2002) 033407 respectiv F. Reinert, G. Nicolay, S. Schmidt, D. Ehm, S. Hufner, Phys. Rev. B 63 (2001) 115415. The experiments are taken at 30K. Bottom panel: the band structure  $E(k_x)$  along the  $\overline{\Gamma M}$  direction.  
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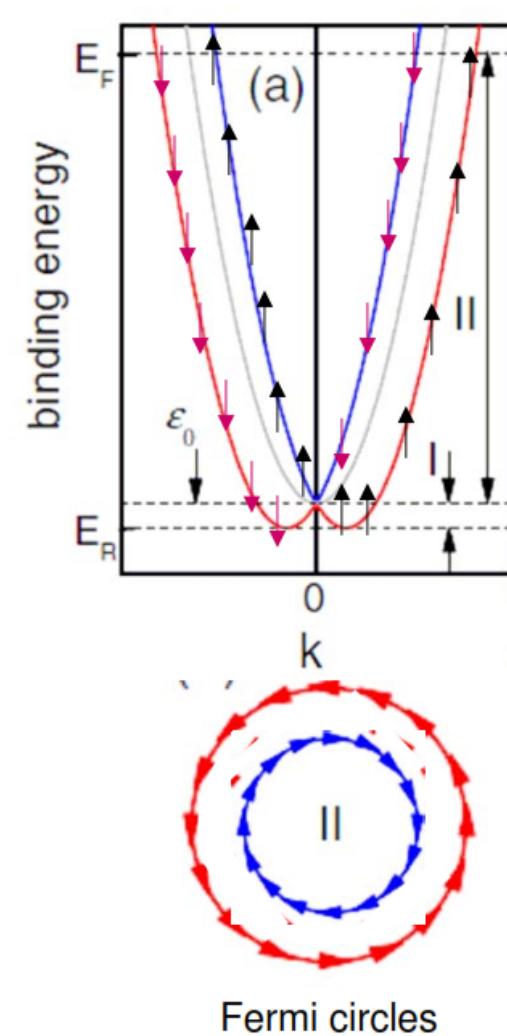
## Rashba effect at interfaces or surfaces of metals



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Bi/Ag(111):  $\alpha_R = 3.05 \text{ eV}\text{\AA}^\circ$

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InGaAs/InAlAs heterostructure	<1	0.028	0.07
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From A. Fert

## Eigenfunctions

The general form of the eigenfunctions within the  $\{|+\rangle, |-\rangle\}$  basis is:

$$|\Psi\rangle = e^{i\vec{k}_{||}\vec{r}} [u|+\rangle + v|-\rangle]$$

Where the amplitude probabilities  $u$  and  $v$  verify the matrix equation:

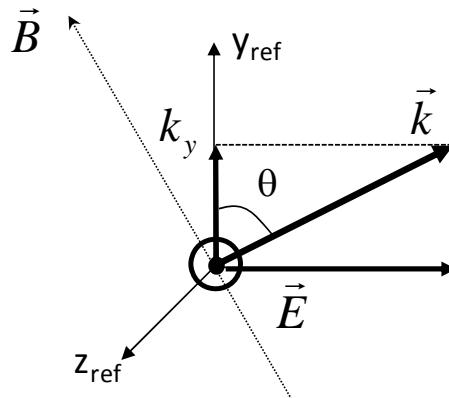
$$(\hat{H} - \lambda \hat{I}) \begin{pmatrix} u \\ v \end{pmatrix} = 0$$

For:  $\lambda_1 = E_+ = \frac{\hbar^2 k_{||}^2}{2m} + \alpha_R |k_{||}|$

$$\begin{pmatrix} -\alpha_R k_{||} & \alpha_R (k_y + ik_x) \\ \alpha_R (k_y - ik_x) & -\alpha_R k_{||} \end{pmatrix} \begin{pmatrix} u \\ v \end{pmatrix} = 0$$

Leads to 2 equivalent equations:

$$\begin{cases} -uk_{||} + v(k_y + ik_x) = 0 \\ u(k_y - ik_x) - vk_{||} = 0 \end{cases}$$



$$u = \frac{k_y + ik_x}{k_{||}} v$$

$$\begin{cases} k_x = k_{||} \sin \theta \\ k_y = k_{||} \cos \theta \end{cases}$$

Combined with the orthonormalization condition:  $u^2 + v^2 = 1$

$$u = ve^{i\theta}$$

$$u = \frac{1}{\sqrt{2}} e^{\frac{i\theta}{2}}; \quad v = \frac{1}{\sqrt{2}} e^{-\frac{i\theta}{2}}$$

For:  $\lambda_1 = E_- = \frac{\hbar^2 k_{||}^2}{2m} - \alpha_R |k_{||}|$

$$|\Psi_{E+}\rangle = \frac{e^{i(k_x x + k_y y)}}{\sqrt{2}} \left( e^{\frac{i\theta}{2}} |+\rangle + e^{-\frac{i\theta}{2}} |-\rangle \right)$$

$$|\Psi_{E-}\rangle = \frac{e^{i(k_x x + k_y y)}}{\sqrt{2}} \left( e^{\frac{i\theta}{2}} |+\rangle - e^{-\frac{i\theta}{2}} |-\rangle \right)$$

**Obs:** The states  $|\Psi_{E+}\rangle, |\Psi_{E-}\rangle$  are stationary states of the system

- Furthermore, we study the time evolution, solving the time dependent Schrodinger equation. Then, by calculating average values of the spin operators  $S_x, S_y, S_z$  we can demonstrate and discuss the spin precession .

To describe the time evolution of the system we use the expression of the solution of the Schrodinger equation projected on the  $\{|\Psi_{E+}\rangle, |\Psi_{E-}\rangle\}$  basis:

$$|\Psi(t)\rangle = |\Psi_{E+}\rangle e^{-\frac{i}{\hbar}E_+t} + |\Psi_{E-}\rangle e^{-\frac{i}{\hbar}E_-t}$$

The 2 eigenstates can be written as:  $E_{\pm}(k_{||}) = \frac{\hbar^2 k_{||}^2}{2m} \pm \alpha_R |k_{||}| = \hbar\omega_0 \pm \alpha_R |k_{||}|$

Within the  $\{|+\rangle, |-\rangle\}$  basis

$$\left[ \begin{array}{l} |\Psi_{E+}\rangle = \frac{e^{i(k_x x + k_y y)}}{\sqrt{2}} \left( e^{\frac{i\theta}{2}} |+\rangle + e^{-\frac{i\theta}{2}} |-\rangle \right) \\ |\Psi_{E-}\rangle = \frac{e^{i(k_x x + k_y y)}}{\sqrt{2}} \left( e^{\frac{i\theta}{2}} |+\rangle - e^{-\frac{i\theta}{2}} |-\rangle \right) \end{array} \right]$$

$$|\Psi(t)\rangle = \frac{e^{i\vec{k}_{||}\vec{r}}}{\sqrt{2}} \left\{ \left( e^{\frac{i\theta}{2}} |+\rangle + e^{-\frac{i\theta}{2}} |-\rangle \right) e^{-\frac{i}{\hbar}(\hbar\omega_0 + \alpha_R k_{||})t} + \left( e^{\frac{i\theta}{2}} |+\rangle - e^{-\frac{i\theta}{2}} |-\rangle \right) e^{-\frac{i}{\hbar}(\hbar\omega_0 - \alpha_R k_{||})t} \right\}$$

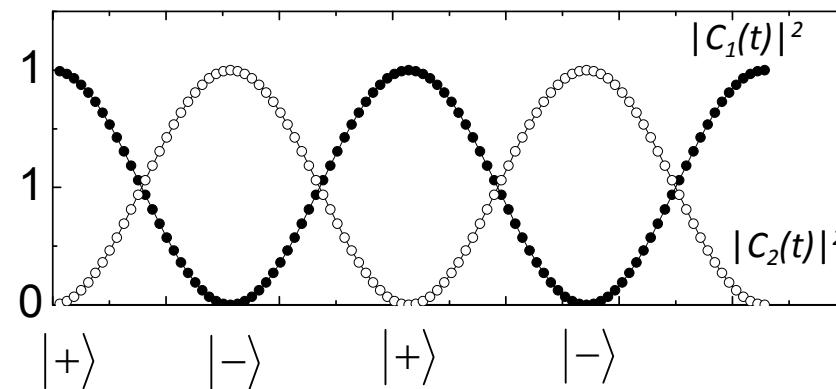
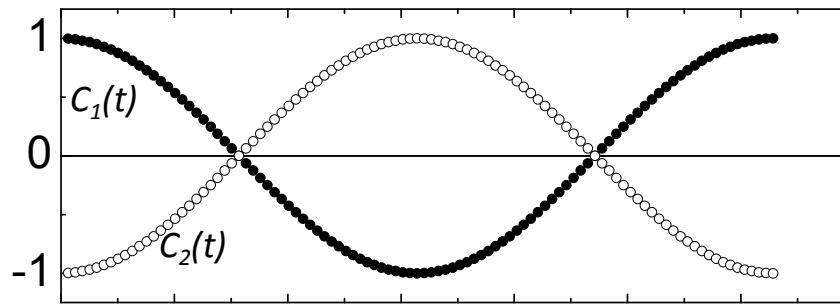
$$|\Psi(t)\rangle = \frac{e^{i(\vec{k}_{||}\vec{r} - \omega_0 t)}}{\sqrt{2}} \left\{ e^{\frac{i\theta}{2}} \left( e^{-\frac{i}{\hbar}\alpha_R k_{||}t} + e^{+\frac{i}{\hbar}\alpha_R k_{||}t} \right) |+\rangle + e^{-\frac{i\theta}{2}} \left( e^{-\frac{i}{\hbar}\alpha_R k_{||}t} - e^{+\frac{i}{\hbar}\alpha_R k_{||}t} \right) |-\rangle \right\}$$

➡

$$|\Psi(t)\rangle = \frac{e^{i(\vec{k}_{||}\vec{r} - \omega_0 t)}}{\sqrt{2}} \left\{ e^{\frac{i\theta}{2}} \cos \frac{\alpha_R k_{||} t}{\hbar} |+\rangle - ie^{-\frac{i\theta}{2}} \sin \frac{\alpha_R k_{||} t}{\hbar} |-\rangle \right\}$$

If one define the amplitudes of probability:

$$|\Psi(t)\rangle^2 \rightarrow \begin{cases} |C_1(t)|^2 \propto \cos^2 \frac{\alpha_R k_{||} t}{\hbar} \\ |C_2(t)|^2 \propto \sin^2 \frac{\alpha_R k_{||} t}{\hbar} \end{cases}$$



Flip-flop movement between the two unstationary states:  
 $|+\rangle, |-\rangle$

## Precession with Larmor frequency

In order to demonstrate the spin precession, one has to calculate the average values of the spin operators:

$\langle \hat{S}_x(t) \rangle, \langle \hat{S}_y(t) \rangle, \langle \hat{S}_z(t) \rangle$  within the basis:  $\{|\Psi_{E+}\rangle, |\Psi_{E-}\rangle\}$

$$|\Psi(t)\rangle = \frac{e^{i(\vec{k}_{||}\vec{r}-\omega_0 t)}}{\sqrt{2}} \left\{ e^{\frac{i\theta}{2}} \cos \frac{\alpha_R k_{||} t}{\hbar} |+\rangle - i e^{-\frac{i\theta}{2}} \sin \frac{\alpha_R k_{||} t}{\hbar} |-\rangle \right\} = C_+(t)|+\rangle + C_-(t)|-\rangle$$

$$\begin{cases} C_+(t) = e^{\frac{i\theta}{2}} \frac{e^{i(\vec{k}_{||}\vec{r}-\omega_0 t)}}{\sqrt{2}} \cos \frac{\alpha_R k_{||} t}{\hbar} \\ C_-(t) = -i e^{-\frac{i\theta}{2}} \frac{e^{i(\vec{k}_{||}\vec{r}-\omega_0 t)}}{\sqrt{2}} \sin \frac{\alpha_R k_{||} t}{\hbar} \end{cases}$$

$$\langle \hat{S}_z \rangle = \langle \Psi | \hat{S}_z | \Psi \rangle = \frac{\hbar}{2} (C_+^* C_+ - C_-^* C_-)$$

$$\langle \hat{S}_x \rangle = \langle \Psi | \hat{S}_x | \Psi \rangle = \frac{\hbar}{2} (C_+^* C_- - C_-^* C_+)$$

$$\langle \hat{S}_y \rangle = \langle \Psi | \hat{S}_y | \Psi \rangle = \frac{\hbar}{2} (C_+^* C_- - C_-^* C_+)$$



$$\langle \hat{S}_z \rangle = \frac{\hbar}{2} [C_+^* C_+ - C_-^* C_-] = \frac{\hbar}{4} \left[ \cos^2 \left( \frac{\alpha_R k_{\parallel}}{\hbar} t \right) - \sin^2 \left( \frac{\alpha_R k_{\parallel}}{\hbar} t \right) \right] = \frac{\hbar}{4} \cos \left( \frac{2\alpha_R k_{\parallel}}{\hbar} t \right)$$

$$\langle \hat{S}_x \rangle = \hbar \Re e [C_+^* C_-] = \frac{\hbar}{2} \Re e \left[ e^{\frac{-i\theta}{2}} \cos \frac{\alpha_R k_{\parallel} t}{\hbar} \sin \frac{\alpha_R k_{\parallel} t}{\hbar} \left( -ie^{-\frac{i\theta}{2}} \right) \right] = -\frac{\hbar}{2} \cos \frac{\alpha_R k_{\parallel} t}{\hbar} \sin \frac{\alpha_R k_{\parallel} t}{\hbar} \Re e \left( ie^{-i\theta} \right) = -\frac{\hbar}{4} \sin \frac{2\alpha_R k_{\parallel} t}{\hbar} \sin \theta$$

$$\langle \hat{S}_y \rangle = \hbar \Im m [C_+^* C_-] = -\frac{\hbar}{4} \sin \frac{2\alpha_R k_{\parallel} t}{\hbar} \cos \theta$$

$\rightarrow$

$$\begin{cases} \langle \hat{S}_x \rangle = -\frac{\hbar}{4} \sin \frac{2\alpha_R k_{\parallel} t}{\hbar} \sin \theta \\ \langle \hat{S}_y \rangle = -\frac{\hbar}{4} \sin \frac{2\alpha_R k_{\parallel} t}{\hbar} \cos \theta \\ \langle \hat{S}_z \rangle = \frac{\hbar}{4} \cos \frac{2\alpha_R k_{\parallel} t}{\hbar} \end{cases}$$

If we denote by:

$$\Omega = \frac{2\alpha_R k_{\parallel}}{\hbar}$$

$\rightarrow$

$$\begin{cases} \langle \hat{S}_x \rangle \propto \sin \Omega t \sin \theta \\ \langle \hat{S}_y \rangle \propto \Omega t \cos \theta \\ \langle \hat{S}_z \rangle \propto \cos \Omega t \end{cases}$$

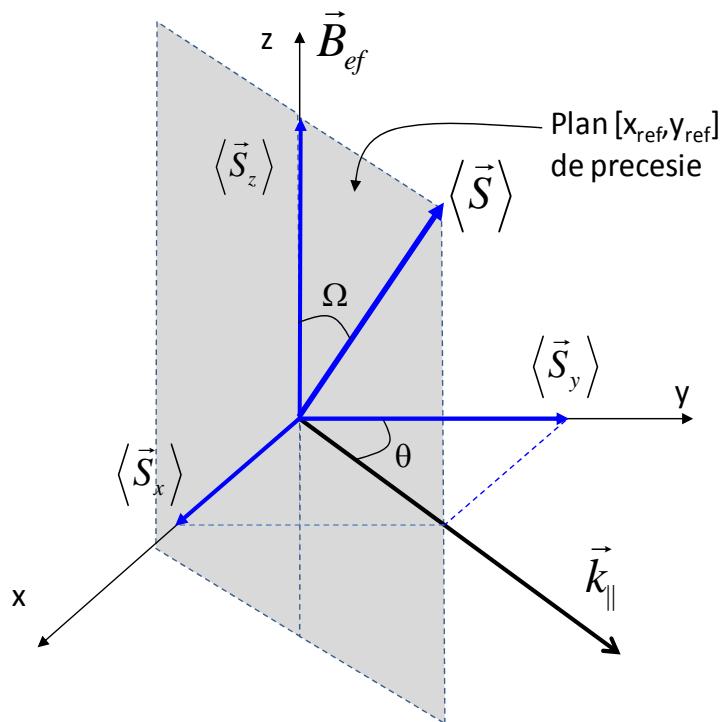
The period of this precession is:

$$T = \frac{2\pi}{\Omega} = \frac{\pi\hbar}{\alpha_R k_{\parallel}}$$

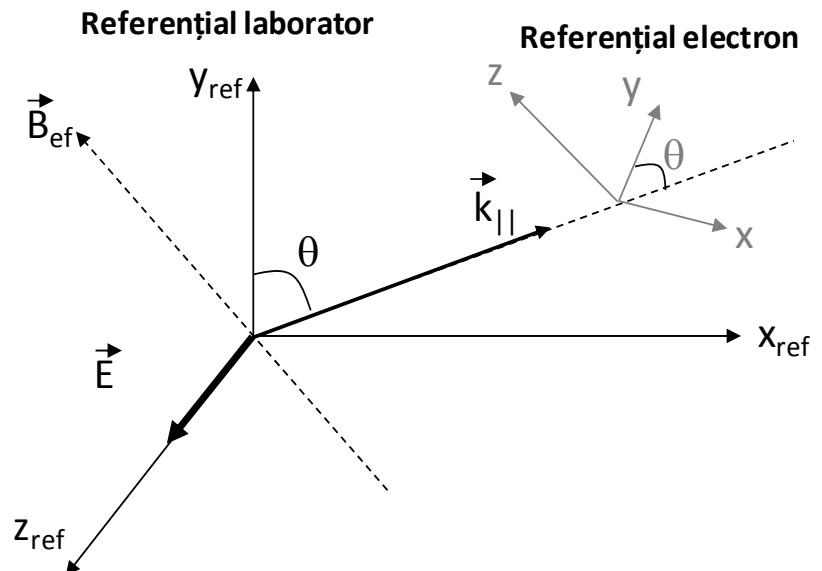
Precession equations of the spin angular momentum  $\mathbf{S}$  with the frequency  $\Omega$  analogous to the Larmor precession around  $\mathbf{B}_{\text{eff}}$

To be dephased with  $\pi$ , the spin has to travel a distance corresponding to a half-period:  $T_L = \frac{\pi\hbar}{2\alpha_R k_{\parallel}}$

In the Datta@Das transistor, the distance between source and drain is adjusted to insure the rotation with  $\pi$  when E of the gate is turned on



Vector diagram within the electron referential



Vector diagram within the lab referential